

LT6013/LT6014

Single/Dual 145µA, 9.5nV/√Hz, A_V ≥5, Rail-to-Rail Output Precision Op Amps

DESCRIPTION

The LT[®]6013 and LT6014 op amps combine low noise and high precision input performance with low power consumption and rail-to-rail output swing. The amplifiers are stable in a gain of 5 or more and feature greatly improved CMRR and PSRR versus frequency compared to other precision op amps.

Input offset voltage is factory-trimmed to less than 35μ V. The low drift and excellent long-term stability ensure a high accuracy over temperature and time. The 250pA maximum input bias current and 120dB minimum voltage gain further maintain this precision over operating conditions.

The LT6013 and LT6014 operate from any supply voltage from 2.7V to 36V and draw only 145μ A of supply current per amplifier on a 5V supply. The output swings to within 40mV of either supply rail, making the amplifiers very useful for low voltage single supply operation.

The amplifiers are fully specified at 5V and \pm 15V supplies and from -40°C to 85°C. The single LT6013 and dual LT6014 are both available in SO-8 and space saving 3mm × 3mm DFN packages. For unity gain stable versions, refer to the LT6010 and LT6011 data sheets.

T, LTC and LT are registered trademarks of Linear Technology Corporation. All other trademarks are the property of their respective owners.

FEATURES

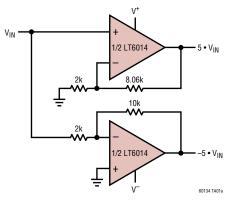
- 35μV Maximum Offset Voltage (LT6013A)
- Low 1/f Noise: 200nV_{P-P} (0.1Hz to 10Hz) 40nV_{RMS} (0.1Hz to 10Hz)
- Low White Noise: 9.5nV/√Hz (1kHz)
- Rail-to-Rail Output Swing
- 145µA Supply Current per Amplifier
- 250pA Maximum Input Bias Current (LT6013A)
- $A_V \ge 5$ Stable; Up to 500pF C_{LOAD}
- 0.2V/µs Slew Rate
- 1.4MHz Gain Bandwidth Product
- 120dB Minimum Voltage Gain, V_S = ±15V
- 0.8µV/°C Maximum V_{OS} Drift
- 2.7V to ±18V Supply Voltage Operation
- Operating Temperature Range: –40°C to 85°C
- Available in SO-8 and Space Saving 3mm × 3mm DFN Packages

APPLICATIONS

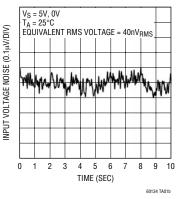
- Thermocouple Amplifiers
- Precision Photodiode Amplifiers
- Instrumentation Amplifiers
- Battery-Powered Precision Systems
- Low-Voltage Precision Systems
- Micro-Power Sensor Interface

TYPICAL APPLICATION

Gain of 10 Single Ended to Differential Converter



LT6013/LT6014 0.1Hz to 10Hz Voltage Noise

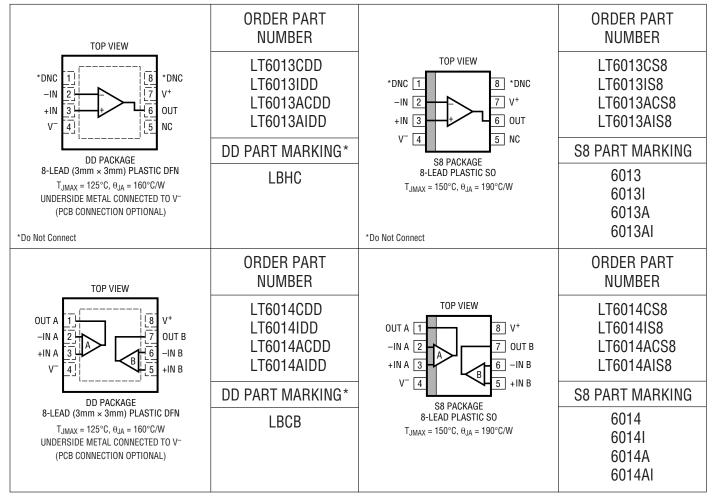


ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V ⁺ to V ⁻)	40V
Differential Input Voltage (Note 2)	
Input Voltage	V+ to V ⁻
Input Current (Note 2)	±10mA
Output Short-Circuit Duration (Note 3)	Indefinite
Operating Temperature Range (Note 4)	-40°C to 85°C
Specified Temperature Range (Note 5)	-40°C to 85°C

Maximum Junction Temperature	
DD Package	125°C
S8 Package	150°C
Storage Temperature Range	
DD Package	
S8 Package	
Lead Temperature (Soldering, 10 sec).	300°C

PACKAGE/ORDER INFORMATION



*Temperature and electrical grades are identified by a label on the shipping container. Consult LTC Marketing for parts specified with wider operating temperature ranges.



ELECTRICAL CHARACTERISTICS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 5V$, 0V; $V_{CM} = 2.5V$; R_L to 0V; unless otherwise specified. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage (Note 8)	LT6013AS8 $T_A = 0^{\circ}C$ to $70^{\circ}C$ $T_A = -40^{\circ}C$ to $85^{\circ}C$	•		10	35 60 75	µV µV µV
		LT6013S8, LT6014AS8 $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		20	60 85 110	μV μV μV
		LT6013ADD $T_A = 0^{\circ}C$ to $70^{\circ}C$ $T_A = -40^{\circ}C$ to $85^{\circ}C$	•		20	60 110 150	μV μV μV
		LT6014S8 $T_A = 0^{\circ}C$ to $70^{\circ}C$ $T_A = -40^{\circ}C$ to $85^{\circ}C$	•		20	75 100 125	νμ γμ γμ
		LT6013DD, LT6014ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		30	85 135 170	νμ γμ γμ
		LT6014DD $T_A = 0^{\circ}C$ to $70^{\circ}C$ $T_A = -40^{\circ}C$ to $85^{\circ}C$	•		30	125 175 210	νμ ν γμ
$\Delta V_{0S}/\Delta T$	Input Offset Voltage Drift (Note 6)	S8 Packages DD Packages	•		0.2 0.2	0.8 1.4	μV/°C μV/°C
I _{OS}	Input Offset Current (Note 8)	LT6013AS8, LT6013ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	250 500 600	pA pA pA
		LT6014AS8, LT6014ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	500 600 700	рА рА рА
		LT6013/LT6014 (Standard grades) $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		150	800 1000 1200	рА рА рА
I _B	Input Bias Current (Note 8)	LT6013AS8, LT6013ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	±250 ±500 ±600	рА рА рА
		LT6013S8, LT6013DD, LT6014AS8, LT6014ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	±400 ±600 ±800	рА рА рА
		LT6014S8, LT6014DD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		150	±800 ±1000 ±1200	рА рА рА
e _n	Input Noise Voltage Density	f = 1kHz, LT6013/LT6014 f = 1kHz, LT6013A/LT6014A			9.5 9.5	13	nV/√Hz nV/√Hz
	Input Noise Voltage (Low Frequency)	Bandwidth = 0.01Hz to 1Hz			200 50		nV _{P-P} nV _{RMS}
		Bandwidth = 0.1Hz to 10Hz			200 40		nV _{P-P} nV _{RMS}



ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_S = 5V, 0V; V_{CM} = 2.5V; R_L to 0V; unless otherwise specified. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
in	Input Noise Current Density	f = 1kHz			0.15		pA/√Hz
	Input Noise Current (Low Frequency)	Bandwidth = 0.01Hz to 1Hz			7 1.3		pA _{P-P} pA _{RMS}
		Bandwidth = 0.1Hz to 10Hz			5 0.4		рА _{Р-Р} рА _{RMS}
R _{IN}	Input Resistance	Common Mode, V _{CM} = 1V to 3.8V Differential			120 20		GΩ MΩ
CIN	Input Capacitance				4		pF
V _{CM}	Input Voltage Range (Positive) Input Voltage Range (Negative)	Guaranteed by CMRR Guaranteed by CMRR	•	3.8	4 0.7	1	V V
CMRR	Common Mode Rejection Ratio	V _{CM} = 1V to 3.8V	•	107	135		dB
	Minimum Supply Voltage	Guaranteed by PSRR	•		2.4	2.7	V
PSRR	Power Supply Rejection Ratio	V_S = 2.7V to 36V, V_{CM} = 1/2V_S	•	112	135		dB
A _{VOL}	Large-Signal Voltage Gain	$ \begin{array}{l} R_L = 10k, V_{OUT} = 1V \text{ to } 4V \\ R_L = 2k, V_{OUT} = 1V \text{ to } 4V \end{array} $	•	300 250	2000 2000		V/mV V/mV
	Channel Separation	V _{OUT} = 1V to 4V, LT6014	•	110	140		dB
V _{OUT}	Maximum Output Swing (Positive, Referred to V ⁺)	No Load, 50mV Overdrive	•		35	55 65	mV mV
		I _{SOURCE} = 1mA, 50mV Overdrive	•		120	170 220	mV mV
	Maximum Output Swing (Negative, Referred to 0V)	No Load, 50mV Overdrive	•		40	55 65	mV mV
		I _{SINK} = 1mA, 50mV Overdrive	•		150	225 275	mV mV
I _{SC}	Output Short-Circuit Current (Note 3)	V _{OUT} = 0V, 1V Overdrive, Source	•	8 4	14		mA mA
		$V_{OUT} = 5V, -1V$ Overdrive, Sink	•	8 4	21		mA mA
SR	Slew Rate	$A_V = -10, R_F = 50k, R_G = 5k$ $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	•	0.15 0.12 0.1	0.2		V/μs V/μs V/μs
GBW	Gain Bandwidth Product	f = 10kHz	•	1 0.9	1.4		MHz MHz
ts	Settling Time	$A_V = -4$, 0.01%, $V_{OUT} = 1.5V$ to 3.5V			20		μS
t _r , t _f	Rise Time, Fall Time	A _V = 5, 10% to 90%, 0.1V Step			1		μS





ELECTRICAL CHARACTERISTICS temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 5V$, 0V; $V_{CM} = 2.5V$; R_L to 0V; unless otherwise specified. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
ΔV_{0S}	Offset Voltage Match (Note 7)	LT6014AS8			50	120	μV
		$T_A = 0^{\circ}C$ to 70°C	•			170	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			220	μV
		LT6014ADD			50	170	μV
		$T_A = 0^{\circ}C$ to 70°C	•			270	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			340	μV
		LT6014S8			50	150	μV
		$T_A = 0^{\circ}C$ to 70°C	•			200	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			250	μV
		LT6014DD			60	250	μV
		$T_A = 0^{\circ}C$ to 70°C	•			350	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			420	μV
ΔI_B	Input Bias Current Match (Note 7)	LT6014AS8, LT6014ADD			200	800	рА
		$T_A = 0^{\circ}C$ to 70°C	•			1200	рA
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			1400	pА
		LT6014S8, LT6014DD			300	1600	рА
		$T_A = 0^{\circ}C$ to 70°C	•			2000	pА
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			2400	рА
∆CMRR	Common Mode Rejection Ratio	LT6014	•	101	135		dB
	Match (Note 7)						
∆PSRR	Power Supply Rejection Ratio	LT6014	•	106	135		dB
	Match (Note 7)						
I _S	Supply Current	per Amplifier			145	165	μΑ
		$T_A = 0^{\circ}C$ to 70°C	•			210	μΑ
		$T_A = -40^{\circ}C$ to $85^{\circ}C$				230	μA

The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_S = ±15V, V_{CM} = 0V, R_L to 0V, unless otherwise specified. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{0S}	Input Offset Voltage (Note 8)	LT6013AS8			20	60	μV
		$T_A = 0^{\circ}C$ to $70^{\circ}C$	•			80	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			110	μV
		LT6013S8			25	85	μV
		$T_A = 0^{\circ}C$ to $70^{\circ}C$	•			110	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			135	μV
		LT6013ADD			25	85	μV
		$T_A = 0^{\circ}C$ to $70^{\circ}C$	•			135	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			170	μV
		LT6013DD, LT6014AS8			30	135	μV
		T _A = 0°C to 70°C	•			160	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			185	μV
		LT6014S8			35	150	μV
		$T_A = 0^{\circ}C$ to $70^{\circ}C$	•			175	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			200	μV
		LT6014ADD			35	160	μV
		$T_A = 0^{\circ}C$ to $70^{\circ}C$	•			210	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			225	μV
		LT6014DD			40	200	μV
		$T_A = 0^{\circ}C$ to $70^{\circ}C$	•			250	μV
		$T_A = -40^{\circ}C$ to $85^{\circ}C$	•			275	μV
	1	1	I	1			60134fb



ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}$ C. $V_S = \pm 15$ V, $V_{CM} = 0$ V, R_L to 0V, unless otherwise specified. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
$\Delta V_{0S} / \Delta T$	Input Offset Voltage Drift (Note 6)	S8 Packages DD Packages	•		0.2 0.2	0.8 1.2	μV/°C μV/°C
I _{OS}	Input Offset Current (Note 8)	LT6013AS8, LT6013ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	250 500 600	pA pA pA
		LT6014AS8, LT6014ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	500 600 700	рА рА рА
		LT6013/LT6014 (Standard grades) $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		150	800 1000 1200	рА рА рА
I _B	Input Bias Current (Note 8)	LT6013AS8, LT6013ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	±250 ±500 ±600	рА рА рА
		LT6013S8, LT6013DD, LT6014AS8, LT6014ADD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		100	±400 ±600 ±800	рА рА рА
		LT6014S8, LT6014DD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		150	±800 ±1000 ±1200	рА рА рА
e _n	Input Noise Voltage Density	f = 1kHz, LT6013/LT6014 f = 1kHz, LT6013A/LT6014A			9.5 9.5	13	nV/√Hz nV/√Hz
	Input Noise Voltage (Low Frequency)	Bandwidth = 0.01Hz to 1Hz			200 50		nV _{P-P} nV _{RMS}
		Bandwidth = 0.1Hz to 10Hz			200 40		nV _{P-P} nV _{RMS}
i _n	Input Noise Current Density	f = 1kHz			0.15		pA/√Hz
	Input Noise Current (Low Frequency)	Bandwidth = 0.01Hz to 1Hz			7 1.3		pA _{P-P} pA _{RMS}
		Bandwidth = 0.1Hz to 10Hz			5 0.4		pA _{P-P} pA _{RMS}
R _{IN}	Input Resistance	Common Mode, V _{CM} = ±13.5V Differential			400 20		GΩ MΩ
CIN	Input Capacitance				4		pF
V _{CM}	Input Voltage Range	Guaranteed by CMRR	•	±13.5	±14		V
CMRR	Common Mode Rejection Ratio	V _{CM} = -13.5V to 13.5V	•	115 112	135 135		dB dB
	Minimum Supply Voltage	Guaranteed by PSRR	•		±1.2	±1.35	V
PSRR	Power Supply Rejection Ratio	$V_{\rm S} = \pm 1.35 V \text{ to } \pm 18 V$	•	112	135		dB
A _{VOL}	Large-Signal Voltage Gain	R _L = 10k, V _{OUT} = -13.5V to 13.5V	•	1000 600	2000		V/mV V/mV
		$R_L = 5k, V_{OUT} = -13.5V \text{ to } 13.5V$	•	500 300	1500		V/mV V/mV
	Channel Separation	V _{OUT} = -13.5V to 13.5V, LT6014	•	120	140		dB





ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_S = ±15V, V_{CM} = 0V, R_L to 0V, unless otherwise specified. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OUT}	Maximum Output Swing (Positive, Referred to V ⁺)	No Load, 50mV Overdrive	•		45	80 100	mV mV
		I _{SOURCE} = 1mA, 50mV Overdrive	•		140	195 240	mV mV
	Maximum Output Swing (Negative, Referred to V ⁻)	No Load, 50mV Overdrive	•		45	80 100	mV mV
		I _{SINK} = 1mA, 50mV Overdrive	•		150	250 300	mV mV
I _{SC}	Output Short-Circuit Current (Note 3)	V _{OUT} = 0V, 1V Overdrive (Source)	•	8 5	15		mA mA
		V _{OUT} = 0V, -1V Overdrive (Sink)	•	8 5	20		mA mA
SR	Slew Rate	$A_V = -10, R_F = 50k, R_G = 5k$ $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	•	0.15 0.12 0.1	0.2		V/µs V/µs V/µs
GBW	Gain Bandwidth Product	f = 10kHz	•	1.1 1	1.6		MHz MHz
ts	Settling Time	$A_V = -4, 0.01\%, V_{OUT} = 0V \text{ to } 10V$			40		μS
t _r , t _f	Rise Time, Fall Time	A _V = 5, 10% to 90%, 0.1V Step			0.9		μS
ΔV_{0S}	Offset Voltage Match (Note 7)	LT6014AS8 $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	•		50	270 320 370	μV μV μV
		LT6014ADD $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	•		50	320 420 450	Vպ Vպ Vպ
		LT6014S8 $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	•		70	300 350 400	μV μV μV
		LT6014DD $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	•		80	400 500 550	μV μV μV
Δl _B	Input Bias Current Match (Note 7)	LT6014AS8, LT6014ADD $T_A = 0^{\circ}C$ to $70^{\circ}C$ $T_A = -40^{\circ}C$ to $85^{\circ}C$	•		200	800 1200 1400	pA pA pA
		LT6014S8, LT6014DD $T_A = 0^{\circ}C$ to 70°C $T_A = -40^{\circ}C$ to 85°C	•		300	1600 2000 2400	pA pA pA
∆CMRR	Common Mode Rejection Ratio Match (Note 7)	LT6014	•	109	135		dB
ΔPSRR	Power Supply Rejection Ratio Match (Note 7)	LT6014	•	106	135		dB
Is	Supply Current	per Amplifier $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$	•		200	250 290 310	μΑ μΑ μΑ



ELECTRICAL CHARACTERISTICS

Note 1: Absolute Maximum Ratings are those beyond which the life of the device may be impaired.

Note 2: The inputs are protected by back-to-back diodes and internal series resistors. If the differential input voltage exceeds 10V, the input current must be limited to less than 10mA.

Note 3: A heat sink may be required to keep the junction temperature below absolute maximum ratings.

Note 4: The LT6013C/LT6014C and LT6013I/LT6014I are guaranteed functional over the operating temperature range of -40° C to 85°C.

Note 5: The LT6013C and LT6014C are guaranteed to meet the specified performance from 0°C to 70°C and are designed, characterized and expected to meet specified performance from -40°C to 85°C but is not tested or QA sampled at these temperatures. The LT6013I and LT6014I are guaranteed to meet specified performance from -40°C to 85°C.

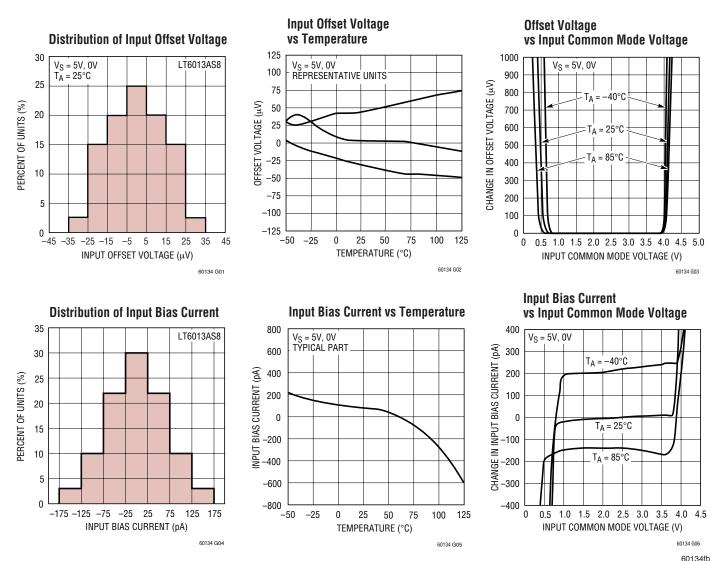
Note 6: This parameter is not 100% tested.

Note 7: Matching parameters are the difference between the two amplifiers. Δ CMRR and Δ PSRR are defined as follows: (1) CMRR and PSRR are measured in μ V/V for the individual amplifiers. (2) The difference between matching amplifiers is calculated in μ V/V. (3) The result is converted to dB.

Note 8: The specifications for V_{OS} , I_B , and I_{OS} depend on the grade and on the package. The following table clarifies the notations.

	STANDARD GRADE	A GRADE
S8 Package	LT6013S8, LT6014S8	LT6013AS8, LT6014AS8
DFN Package	LT6013DD, LT6014DD	LT6013ADD, LT6014ADD

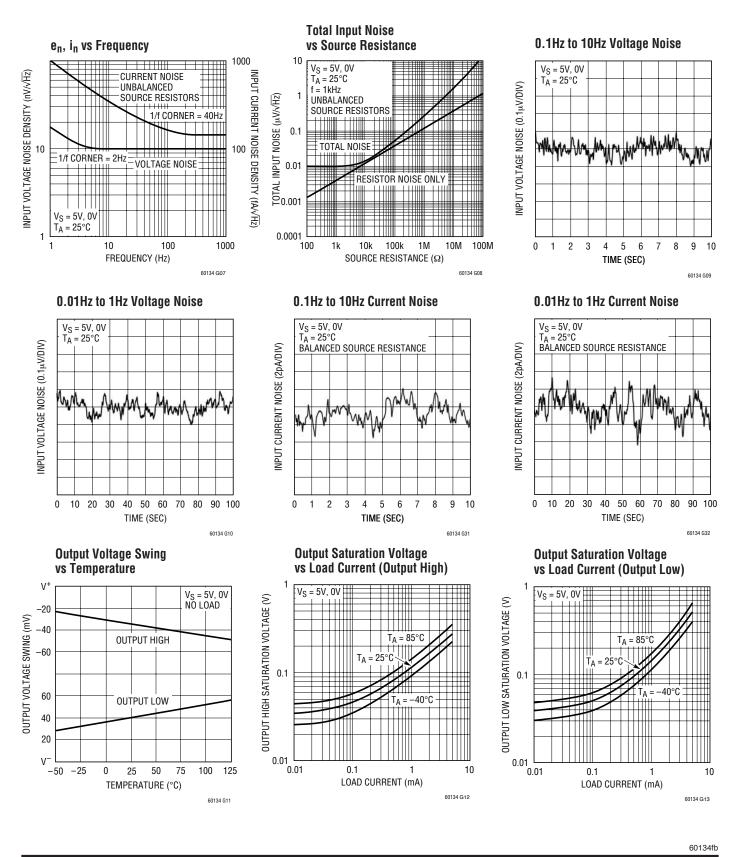
TYPICAL PERFORMANCE CHARACTERISTICS



6013410

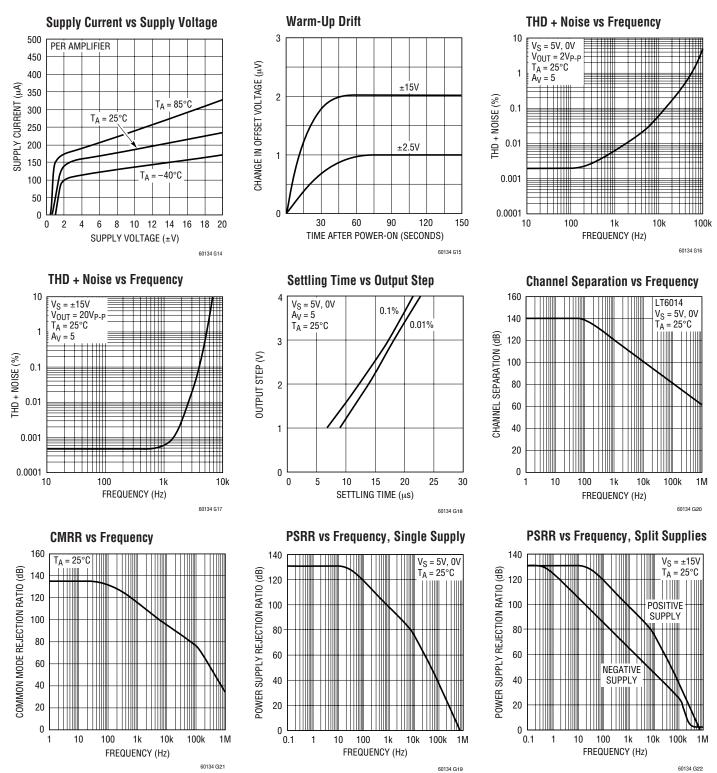


TYPICAL PERFORMANCE CHARACTERISTICS



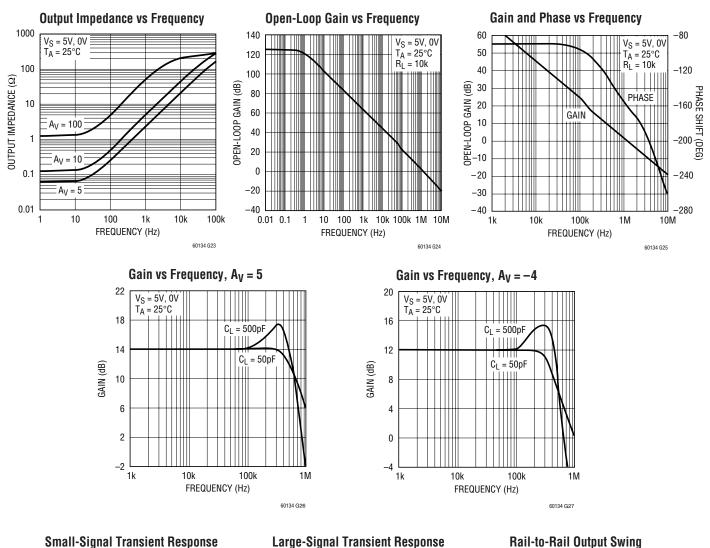


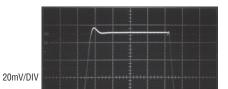
TYPICAL PERFORMANCE CHARACTERISTICS





TYPICAL PERFORMANCE CHARACTERISTICS

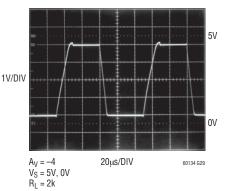




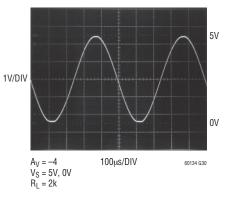
2µs/DIV

60134 G28

Large-Signal Transient Response



Rail-to-Rail Output Swing





 $A_V = 5$

APPLICATIONS INFORMATION

Not Unity-Gain Stable

The LT6013 and LT6014 amplifiers are optimized for the lowest possible noise and smallest package size, and are intentionally decompensated to be stable in a gain configuration of 5 or greater. Do not connect the amplifiers in a gain less than 5 (such as unity-gain). For a unity-gain stable amplifier with similar performance though slightly higher noise and lower bandwidth, see the LT6010 and LT6011/LT6012 datasheets.

Figure 1 shows simple inverting and non-inverting op amp configurations and indicates how to achieve a gain of 5 or greater. For more general feedback networks, determine the gain that the op amp "sees" as follows:

- 1. Suppose the op amp is removed from the circuit.
- 2. Apply a small-signal voltage at the output node of the op amp.

- 3. Find the differential voltage that would appear across the two inputs of the op amp.
- 4. The ratio of the output voltage to the input voltage is the gain that the op amp "sees". This ratio must be 5 or greater.

Do not place a capacitor bigger than 200pF between the output to the inverting input unless there is a 5 times larger capacitor from that input to AC ground. Otherwise, the op amp gain would drop to less than 5 at high frequencies, and the stability of the loop would be compromised.

The LT6013 and LT6014 can be used in lower gain configurations when an impedance is connected between the op amp inputs. Figure 2 shows inverting and non-inverting unity gain connections. The R_C network across the op amp inputs results in a large enough noise gain at high frequencies, thereby ensuring stability. At low frequencies, the capacitor is an open circuit so the DC precision (offset and noise) remains very good.

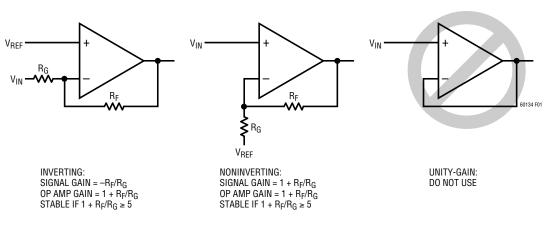
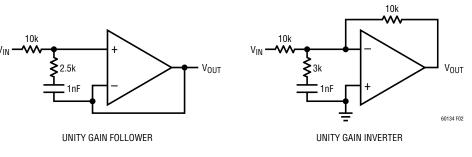


Figure 1. Use LT6013 and LT6014 in a Gain of 5 or Greater







APPLICATIONS INFORMATION

Preserving Input Precision

Preserving the input accuracy of the LT6013 and LT6014 requires that the applications circuit and PC board layout do not introduce errors comparable to or greater than the 10μ V typical offset of the amplifiers. Temperature differentials across the input connections can generate thermocouple voltages of 10's of microvolts so the connections to the input leads should be short, close together and away from heat dissipating components. Air currents across the board can also generate temperature differentials.

The extremely low input bias currents allow high accuracy to be maintained with high impedance sources and feedback resistors. The LT6013 and LT6014 low input bias currents are obtained by a cancellation circuit on-chip. This causes the resulting I_B^+ and I_B^- to be uncorrelated, as implied by the I_{OS} specification being comparable to I_B . Do not try to balance the input resistances in each input lead; instead keep the resistance at either input as low as possible for maximum accuracy.

Leakage currents on the PC board can be higher than the input bias current. For example, $10G\Omega$ of leakage between a 15V supply lead and an input lead will generate 1.5nA! Surround the input leads with a guard ring driven to the same potential as the input common mode to avoid excessive leakage in high impedance applications.

Input Protection

The LT6013/LT6014 features on-chip back-to-back diodes between the input devices, along with 500Ω resistors in series with either input. This internal protection limits the input current to approximately 10mA (the maximum allowed) for a 10V differential input voltage. Use additional external series resistors to limit the input current to 10mA in applications where differential inputs of more than 10V are expected. For example, a 1k resistor in series with each input provides protection against 30V differential voltage.

Input Common Mode Range

The LT6013/LT6014 output is able to swing close to each power supply rail (rail-to-rail out), but the input stage is limited to operating between V^- + 1V and V^+ – 1.2V. Exceeding this common mode range will cause the gain to drop to zero; however, no phase reversal will occur.

Total Input Noise

The LT6013 and LT6014 amplifiers contribute negligible noise to the system when driven by sensors (sources) with impedance between $10k\Omega$ and $1M\Omega$. Throughout this range, total input noise is dominated by the $4kTR_S$ noise of the source. If the source impedance is less than $10k\Omega$, the input voltage noise of the amplifier starts to contribute with a minimum noise of 9.5nV/ \sqrt{Hz} for very low source impedance. If the source impedance is more than $1M\Omega$, the input current noise of the amplifier, multiplied by this high impedance, starts to contribute and eventually dominate. Total input noise spectral density can be calculated as:

$$v_{n(TOTAL)} = \sqrt{e_n^2 + 4kTR_S + (i_nR_S)^2}$$

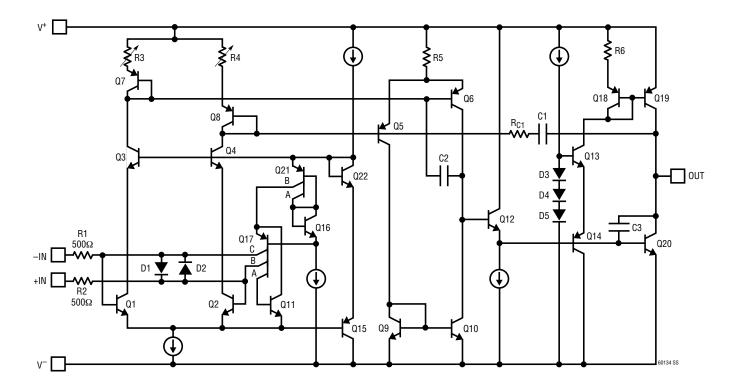
where $e_n = 9.5 \text{nV}/\sqrt{\text{Hz}}$, $i_n = 0.15 \text{pA}/\sqrt{\text{Hz}}$ and R_S is the total impedance at the input, including the source impedance.

Capacitive Loads

The LT6013 and LT6014 can drive capacitive loads up to 500pF at a gain of 5. The capacitive load driving capability increases as the amplifier is used in higher gain configurations. A small series resistance between the output and the load further increases the amount of capacitance that the amplifier can drive.



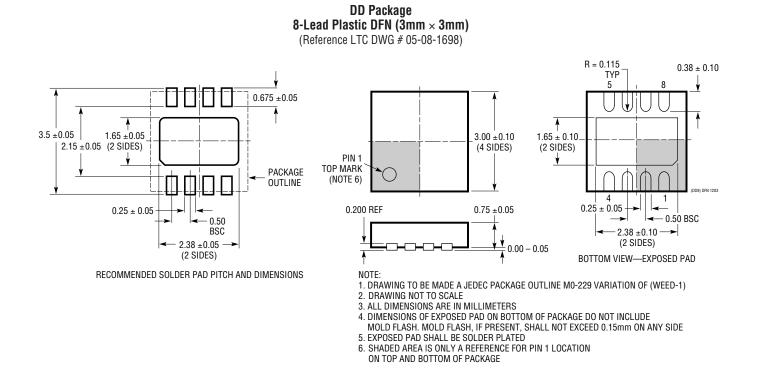
SIMPLIFIED SCHEMATIC (One Amplifier)



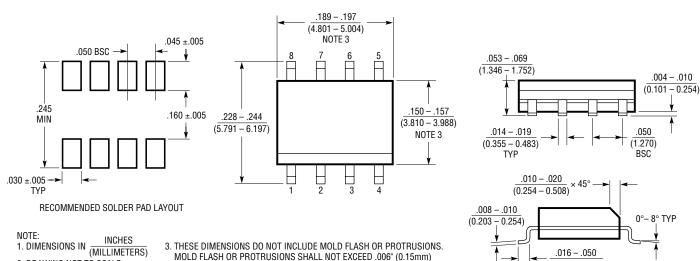




PACKAGE DESCRIPTION



S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .006" (0.15mm)

.016 - .050

(0.406 - 1.270)



SO8 0303



2. DRAWING NOT TO SCALE

Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.